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[Vishay Semiconductor/Diodes Division](#)
[VS-HFA15TB60PBF](#)

For any questions, you can email us directly:

sales@integrated-circuit.com



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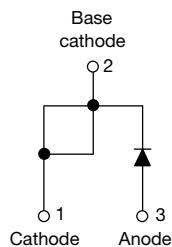
VS-HFA15TB60PbF, VS-HFA15TB60-N3

Vishay Semiconductors

HEXFRED®, Ultrafast Soft Recovery Diode, 15 A



TO-220AC



FEATURES

- Ultrafast and ultrasoft recovery
- Very low I_{RRM} and Q_{rr}
- Designed and qualified according to JEDEC®-JESD47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE
Available

BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION

VS-HFA15TB60... is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 15 A continuous current, the VS-HFA15TB60... is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA15TB60... is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

PRODUCT SUMMARY

Package	TO-220AC
$I_{F(AV)}$	15 A
V_R	600 V
V_F at I_F	1.2 V
t_{rr} typ.	23 ns
T_J max.	150 °C
Diode variation	Single die

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Cathode to anode voltage	V_R		600	V
Maximum continuous forward current	I_F	$T_C = 100$ °C	15	A
Single pulse forward current	I_{FSM}		150	
Maximum repetitive forward current	I_{FRM}		60	
Maximum power dissipation	P_D	$T_C = 25$ °C	74	W
		$T_C = 100$ °C	29	
Operating junction and storage temperature range	T_J, T_{Stg}		-55 to +150	°C



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VS-HFA15TB60PbF, VS-HFA15TB60-N3

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ELECTRICAL SPECIFICATIONS ($T_J = 25^\circ\text{C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V_{BR}	$I_R = 100 \mu\text{A}$		600	-	-	V
Maximum forward voltage	V_{FM}	$I_F = 15 \text{ A}$	See fig. 1	-	1.3	1.7	
		$I_F = 30 \text{ A}$		-	1.5	2.0	
		$I_F = 15 \text{ A}, T_J = 125^\circ\text{C}$		-	1.2	1.6	
Maximum reverse leakage current	I_{RM}	$V_R = V_R \text{ rated}$ $T_J = 125^\circ\text{C}, V_R = 0.8 \times V_R \text{ rated}$	See fig. 2	-	1.0	10	μA
				-	400	1000	
Junction capacitance	C_T	$V_R = 200 \text{ V}$	See fig. 3	-	25	50	pF
Series inductance	L_S	Measured lead to lead 5 mm from package body		-	8.0	-	nH

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25^\circ\text{C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time See fig. 5	t_{rr}	$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$		-	19	-	ns
	t_{rr1}	$T_J = 25^\circ\text{C}$	See fig. 5 $I_F = 15 \text{ A}$ $dI_F/dt = 200 \text{ A}/\mu\text{s}$ $V_R = 200 \text{ V}$	-	42	60	
	t_{rr2}	$T_J = 125^\circ\text{C}$		-	74	120	
Peak recovery current See fig. 6	I_{RRM1}	$T_J = 25^\circ\text{C}$		-	4.0	6.0	A
	I_{RRM2}	$T_J = 125^\circ\text{C}$		-	6.5	10	
Reverse recovery charge See fig. 7	Q_{rr1}	$T_J = 25^\circ\text{C}$	See fig. 6 $V_R = 200 \text{ V}$	-	84	180	nC
	Q_{rr2}	$T_J = 125^\circ\text{C}$		-	241	600	
Peak rate of fall of recovery current during t_b See fig. 8	$dl_{(rec)M}/dt1$	$T_J = 25^\circ\text{C}$	See fig. 6 $V_R = 200 \text{ V}$	-	188	-	$\text{A}/\mu\text{s}$
	$dl_{(rec)M}/dt2$	$T_J = 125^\circ\text{C}$		-	160	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Lead temperature	T_{lead}	0.063" from case (1.6 mm) for 10 s		-	-	300	$^\circ\text{C}$
Thermal resistance, junction to case	R_{thJC}			-	-	1.7	K/W
Thermal resistance, junction to ambient	R_{thJA}	Typical socket mount		-	-	80	
Weight				-	2.0	-	g
				-	0.07	-	oz.
Mounting torque				6.0 (5.0)	-	12 (10)	$\text{kgf} \cdot \text{cm}$ (lbf · in)
Marking device		Case style TO-220AC		HFA15TB60			

VS-HFA15TB60PbF, VS-HFA15TB60-N3

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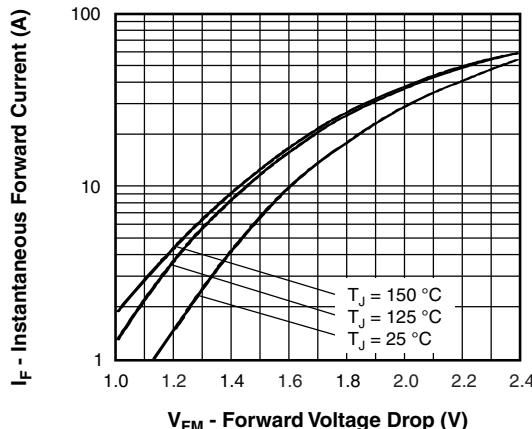


Fig. 1 - Maximum Forward Voltage Drop vs.
Instantaneous Forward Current

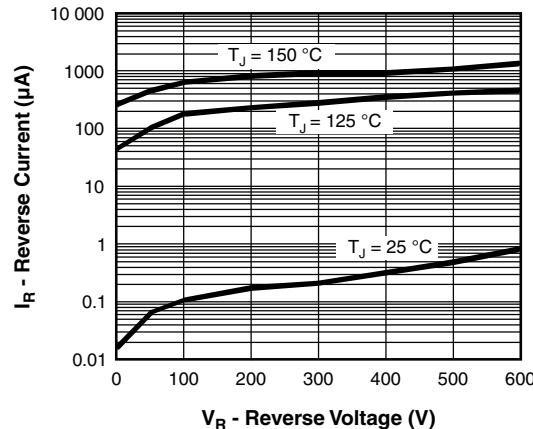


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

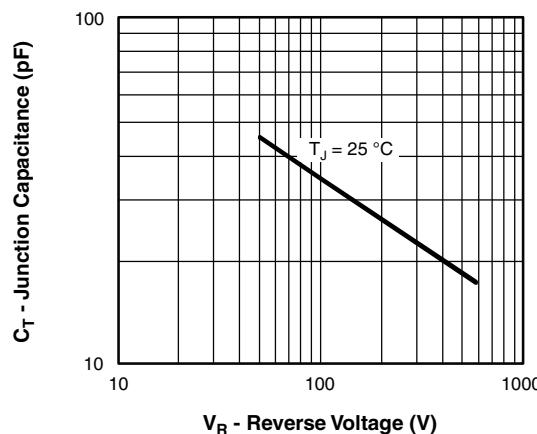


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

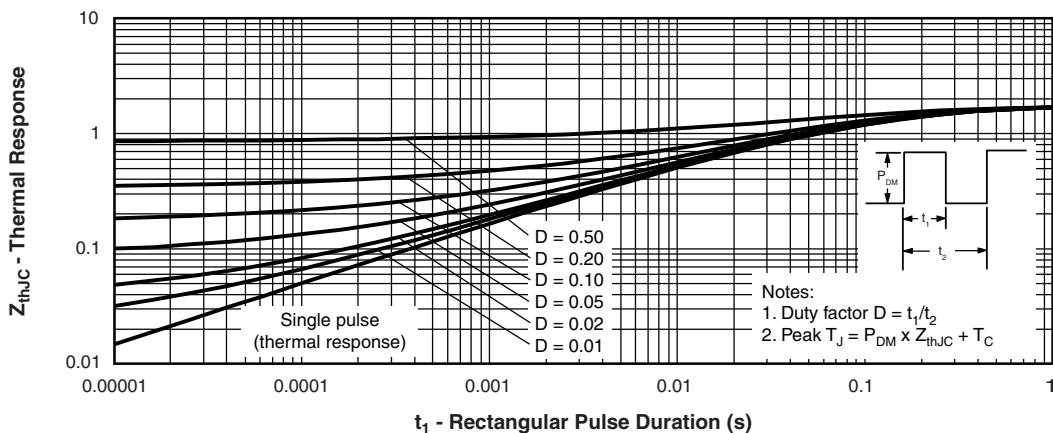


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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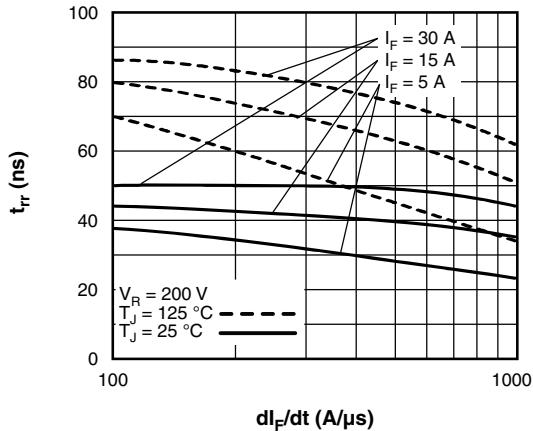


Fig. 5 - Typical Reverse Recovery Time vs. dI_F/dt

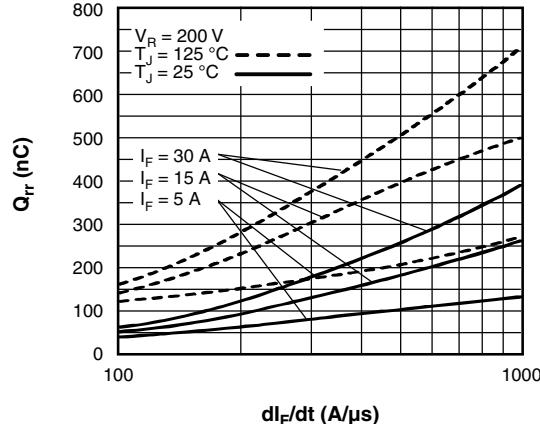


Fig. 7 - Typical Stored Charge vs. dI_F/dt

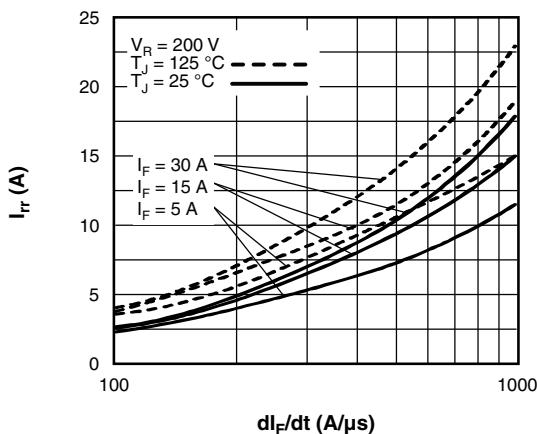


Fig. 6 - Typical Recovery Current vs. dI_F/dt

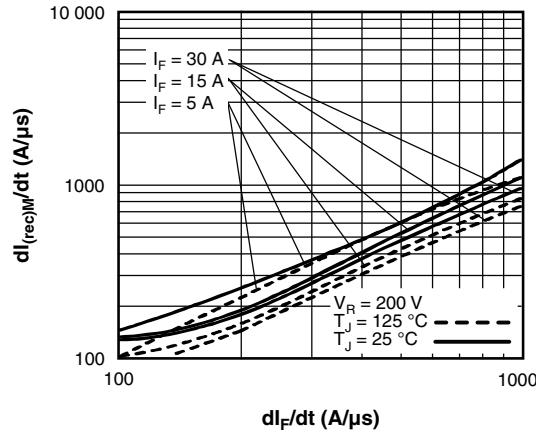


Fig. 8 - Typical $dI_{(rec)M}/dt$ vs. dI_F/dt

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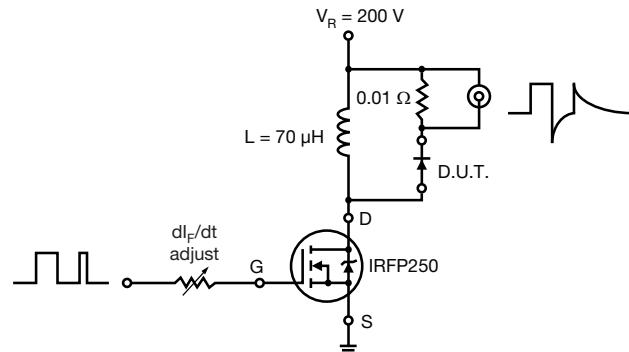


Fig. 9 - Reverse Recovery Parameter Test Circuit

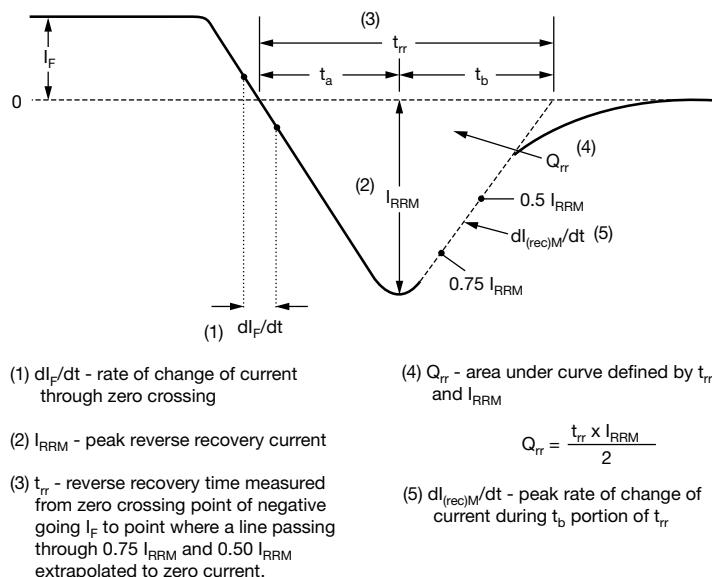


Fig. 10 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE

Device code	VS-	HF	A	15	TB	60	PbF
	1	2	3	4	5	6	7

- 1** - Vishay Semiconductors product
- 2** - HEXFRED® family
- 3** - Electron irradiated
- 4** - Current rating (15 = 15 A)
- 5** - Package:
TB = TO-220AC
- 6** - Voltage rating (60 = 600 V)
- 7** - Environmental digit:
PbF = lead (Pb)-free and RoHS-compliant
-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-HFA15TB60PbF	50	1000	Antistatic plastic tube
VS-HFA15TB60-N3	50	1000	Antistatic plastic tube

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95221
Part marking information	www.vishay.com/doc?95224
	www.vishay.com/doc?95068

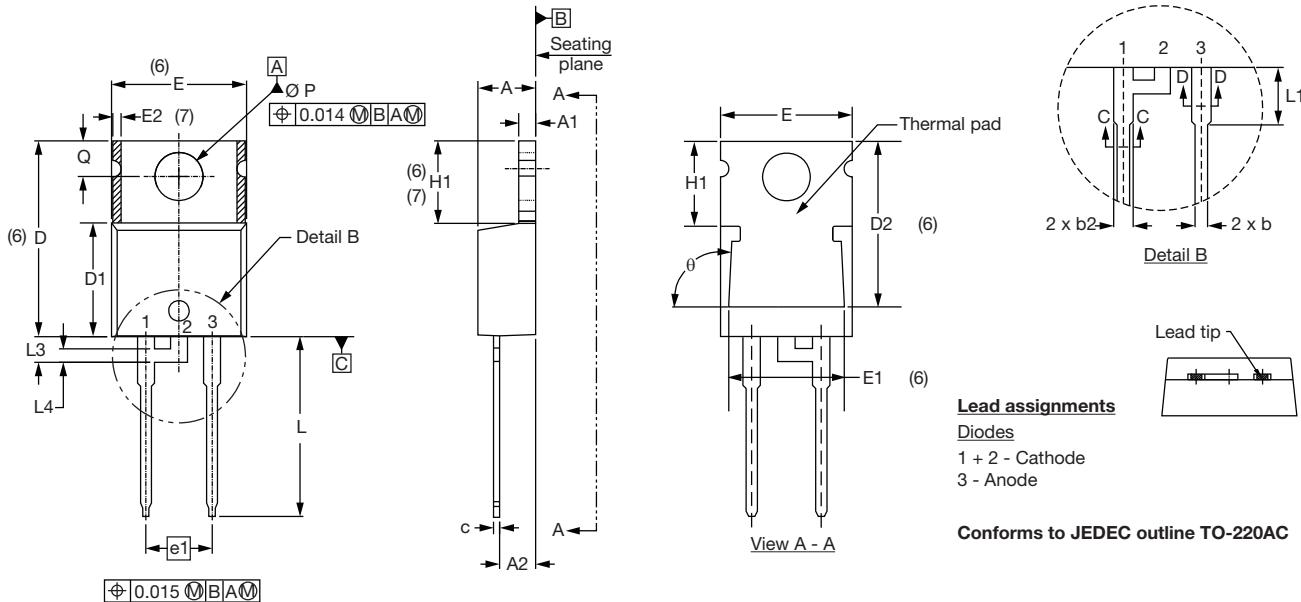


Outline Dimensions

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TO-220AC

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.			MIN.	MAX.	MIN.	MAX.	
A	4.25	4.65	0.167	0.183		E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055		E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115		e	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040		e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4	H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068		L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4	L1	3.32	3.82	0.131	0.150	2
c	0.36	0.61	0.014	0.024		L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4	L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3	Ø P	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355		Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6	θ	90° to 93°		90° to 93°		
E	10.11	10.51	0.398	0.414	3, 6						

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline

**Legal Disclaimer Notice**

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